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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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KSC2310

High Voltage Power Amplifier

- Collector-Base Voltage: V_{CBO}=200V
 Current Gain Bandwidth Product: f_T=100MHz



1. Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	200	V
V _{CEO}	Collector-Emitter Voltage	150	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	50	mA
P _C	Collector Power Dissipation	800	mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{C}=100\mu A, I_{E}=0$	200			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C=5mA$, $I_B=0$	150			٧
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =100μA, I _C =0	5			V
I _{CBO}	Collector Cut-off Current	V _{CB} =200V, I _E =0			0.1	μΑ
h _{FE}	DC Current Gain	V _{CE} =5V, I _C =10mA	40		240	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =10mA, I _B =1mA			0.5	V
f _T	Current Gain Bandwidth Product	V _{CE} =30V, I _C =10mA		100		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz		3.5	5	pF

h_{FE} Classification

Classification	R	0	Υ
h _{FE}	40 ~ 80	70 ~ 140	120 ~ 240

Typical Characteristics

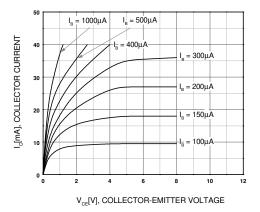


Figure 1. Static Characteristic

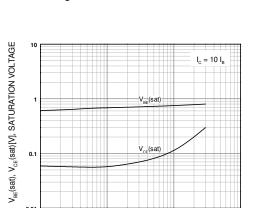


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

 $I_{\rm c}[{\rm mA}],$ COLLECTOR CURRENT

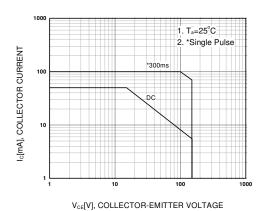
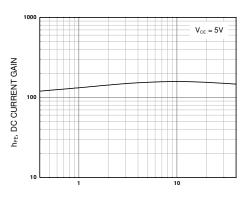


Figure 5. Safe Operating Area



I_c[mA], COLLECTOR CURRENT

Figure 2. DC current Gain

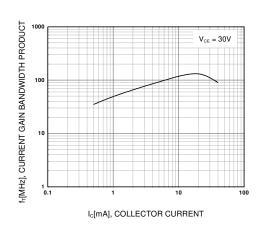


Figure 4. Current Gain Bandwidth Product

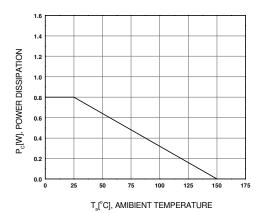


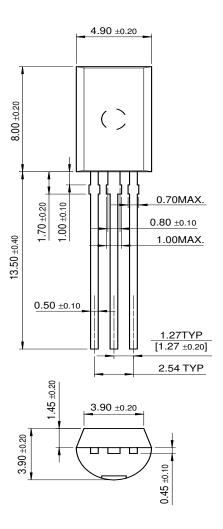
Figure 6. Power Derating

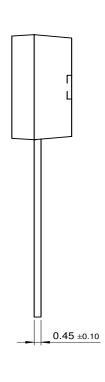
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Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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Rev. I1

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